## 1N66xx Series

## Switching Diodes

## Features

- JAN, JANTX, JANTXV and JANS available per MIL-PRF-19500/578 \&/609

- Non-Cavity Glass Package
- Category I Metallurgically Bonded
- Replacement for 1N4148-1, 1N4150-1, 1N914
- Very Low Capacitance
- Ultra Fast Recovery Time

MELF (US)


Axial

## Electrical Specifications

| Part \# | $\mathrm{V}_{\mathrm{BR}} @ \mathrm{I}_{\mathrm{R}}$ |  | $\mathrm{V}_{\text {RWM }}$ | $\mathrm{V}_{\mathrm{FR}} / \mathrm{t}_{\mathrm{FR}}$ |  | $\mathrm{C}_{\mathrm{T}} 1$ | $\mathrm{C}_{\mathrm{T}} 2$ | trr |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | @ $\mathrm{I}_{\mathrm{F}}=200 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{R}}=0.0 \mathrm{~V}$ | $\mathrm{V}_{\mathrm{R}}=1.5 \mathrm{~V}$ | $\begin{aligned} & \mathrm{I}_{\mathrm{R}}=10 \mathrm{~mA}, \\ & \mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA} \end{aligned}$ |
|  | V(pk) | $\mu \mathrm{A}$ |  | $\mathrm{V}(\mathrm{pk})$ | $\mathrm{V}(\mathrm{pk})$ | ns | pF | pF | ns |
| 1N6638, U \& US | 150 | 100 | 125 | 5 | 20 | 2.5 | 2.0 | 4.5 |
| 1N6639, U \& US | 100 | 10 | 75 | 5 | 10 | 2.5 | - | 4 |
| 1N6640, U \& US | 75 | 10 | 50 | 5 | 10 | 2.5 | - | 4 |
| 1N6641, U \& US | 75 | 10 | 50 | 5 | 10 | 3.0 | - | 5 |
| 1N6642, U \& US | 100 | 100 | 75 | 5 | 20 | 5.0 | 2.8 | 5 |
| 1N6643, U \& US | 75 | 100 | 50 | 5 | 20 | 5.0 | 2.8 | 6 |


| Part \# | $\mathrm{I}_{\mathrm{R}}$ |  |  |  | $\mathbf{V F}_{\mathrm{F}}$ @ $\mathrm{l}_{\mathrm{F}}$ |  |  |  | $I_{\text {F }}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | $\mathrm{V}_{\mathrm{R}}=20 \mathrm{~V}$ | $\mathrm{V}_{\mathrm{R}}=\mathrm{V}_{\mathrm{RWM}}$ | $\begin{gathered} \mathrm{V}_{\mathrm{R}}=20 \mathrm{~V} \\ \mathrm{~T}_{\mathrm{A}}=+150^{\circ} \mathrm{C} \end{gathered}$ | $\begin{gathered} \mathrm{V}_{\mathrm{R}}=\mathrm{V}_{\mathrm{RWM},}, \\ \mathrm{~T}_{\mathrm{A}}=+150^{\circ} \mathrm{C} \end{gathered}$ |  |  | $\mathrm{T}_{\mathrm{A}}=+150^{\circ} \mathrm{C}$ | $\mathrm{T}_{\mathrm{A}}=-55^{\circ} \mathrm{C}$ |  |
|  | nA | nA | $\mu \mathrm{A}$ | $\mu \mathrm{A}$ | V | V | V | V | mA |
|  |  |  |  |  | Min. | Max. | Max. | Max. | (pulsed) |
| 1N6638, U \& US | 35 | 500 | 50 | 100 | - | $\begin{aligned} & 1.1 \\ & 0.8 \end{aligned}$ | $\overline{0.65}$ | $1.2$ | $\begin{gathered} 200 \\ 10 \end{gathered}$ |
| 1N6639, U \& US | - | 100 | - | 90 | - | 1.2 | - | 1.3 | 500 |
| 1N6640, U \& US | - | 100 | - | 90 | $\begin{aligned} & 0.54 \\ & 0.76 \\ & 0.82 \\ & 0.87 \end{aligned}$ | $\begin{gathered} 0.62 \\ 0.86 \\ 0.92 \\ 1.0 \\ \hline \end{gathered}$ | - | $\frac{-}{\overline{-}}$ | $\begin{gathered} \hline 1 \\ 50 \\ 100 \\ 200 \\ \hline \end{gathered}$ |
| 1N6641, U \& US | - | 100 | - | 90 | 0.87 | 1.1 | - | 1.2 | 200 |
| 1N6642, U \& US | 25 | 500 | 50 | 100 | - | $\begin{aligned} & 0.8 \\ & 1.2 \\ & \hline \end{aligned}$ | $0.8$ | $\overline{1.2}$ | $\begin{gathered} 10 \\ 100 \\ \hline \end{gathered}$ |
| 1N6643, U \& US | 50 | 500 | 75 | 100 | - | $\begin{aligned} & 0.8 \\ & 1.2 \end{aligned}$ | $0.8$ | $\overline{1.4}$ | $\begin{gathered} 10 \\ 100 \end{gathered}$ |

## Switching Diodes

## Absolute Maximum Ratings ${ }^{1,2}$

| Parameter | Absolute Maximum |
| :---: | :---: |
| Operating Temperature | $-65^{\circ} \mathrm{C}$ to $+175^{\circ} \mathrm{C}$ |

1. Exceeding any one or combination of these limits may cause permanent damage to this device.
2. VPT Components does not recommend sustained operation near these survivability limits.



FIGURE 4
Typical Reverse Current vs Reverse Voltage

## Note:

All temperatures shown on graphs are junction temperatures


## NOTES:

1. All devices are capable of operating at $\leq$ TJ specified on this curve. Any parallel line to this curve will intersect the appropriate current for the desired maximum TJ allowed.
2. Derate design curve constrained by the maximum junction temperatures and current rating specified. (See 1.3.)
3. Derate design curve chosen at $\mathrm{TJ} \leq 150^{\circ} \mathrm{C}$, where the maximum temperature of electrical test is performed.
4. Derate design curves chosen at $\mathrm{TJ} \leq 125^{\circ} \mathrm{C}$, and $110^{\circ} \mathrm{C}$ to show current rating where most users want to limit TJ intheir application.

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FIGURE 7. Thermal imoedance (axial leads).
$R_{\text {eנl }}=150^{\circ} \mathrm{C} / \mathrm{w}$
$Z_{\text {eJX }}=25^{\circ} \mathrm{C} / \mathrm{W}$ maximum at $t_{\mathrm{H}}=10 \mathrm{~ms}$

Lead spacing $=0$ inch mounted to an infinite heat dissipater

## Switching Diodes

## Outline Drawing



FIGURE 1

| Symbol | Dimensions |  |  |  | Notes |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | Inches |  | Millimeters |  |  |
|  | Min | Max | Min | Max |  |
| BD | .056 | .080 | 1.42 | 2.03 | 2 |
| BL | .130 | .180 | 3.30 | 4.57 |  |
| LD | .018 | .022 | .046 | 0.56 | 3 |
| LL | 1.00 | 1.50 | 25.40 | 38.10 |  |



FIGURE 2

| Symbol | Dimensions |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | Inches |  | Millimeters |  |
|  | Min | Max | Min | Max |
| D | .070 | .085 | 1.78 | 2.16 |
| B | .165 | .195 | 4.19 | 4.95 |
| ECT | .019 | .028 | .048 | 0.71 |
| S | .003 |  | 0.08 |  |

## LEADED DESIGN DATA

CASE: D-5D, Hermetically sealed glass case, per MIL-PRF-19500/578 \& /609
LEAD FINISH: Tin/Lead
LEAD MATERIAL: Copper clad steel POLARITY: Cathode end is banded. PACKAGE WEIGHT: 0.150 g

## U \& US DESIGN DATA

CASE: D-5D, Hermetically sealed glass case, per MIL-PRF-19500/578 \& /609
LEAD FINISH: Tin/Lead
END CAP MATERIAL (U, US): Copper POLARITY: Cathode end is banded. PACKAGE WEGGHT: 0.095 g
MOUNTING SURFACE SELECTION: The Axial Coefficient of Expansion (COE of this device is approximately $+4 \mathrm{PPM} /{ }^{\circ} \mathrm{C}$. The COE of the Mounting Surface System should be selected to provide a suitable match with this device.

## NOTES:

1. Dimensions are in inches. Millimeters are given for general information only.
2. Dimension $B D$ shall be measured at the largest diameter.
3. The specified lead diameter applies in the zone between . 050 inch ( 1.27 mm ) from the diode body to the end of the lead. Outside of this zone lead shall not exceed BD.
4. In accordance with ASME 14.5 M , diameters are equivalent to $\Phi x$ symbology.
5. U-suffix parts are structurally identical to the US-suffix parts.

## Suggested Minimum Footprints <br> D-5D (D-BODY) U, US DIODES



FIGURE 8

## NOTES:

1. Dimensions are in inches / mm.
2. The dimensions listed will match the device terminals based on worst-case package outline drawings and assuming accuracy of device placements is within 0.005 inches. Footprints also provide for solder filets at the outer ends of the device at least as wide as the terminals.
3. F designates recommendation to fill unused area with an extended copper pad in order to reduce the CTE difference between the device and the PC board. The extended area may be3 coated with a solder mask. the width of F depends upon your PCB design rules.

## Switching Diodes

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